

Supporting information

Photoelectrochemical-driven nitrogen reduction to ammonia by $V_o\text{-SnO}_2/\text{TiO}_2$ composite electrode

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Table. S1 Resistance and CPE values of the corresponding models for the sample of TiO₂-SnO₂/TiO₂ and V_o-SnO₂/TiO₂ nanorod arrays at different solvothermal times.

Catalysts	<i>R</i> _s (Ω)	CPE1		<i>R</i> ₁ (Ω)	CPE2		<i>R</i> _{ct} (Ω)
		<i>Q</i> ₁ (F)	<i>n</i> ₁ (F)		<i>Q</i> ₂ (F)	<i>n</i> ₂ (μF)	
TiO ₂	31.32	1.03*10 ⁻⁵	0.84	130.08	1.36*10 ⁻⁴	0.68	5370
SnO ₂ -8/TiO ₂	30.26	3.41*10 ⁻⁴	0.80	35.52	2.61*10 ⁻⁴	0.80	4130
SnO ₂ -16/TiO ₂	31.61	1.55*10 ⁻⁴	0.85	93.11	1.94*10 ⁻⁴	0.68	3171
SnO ₂ -24/TiO ₂	31.11	2.85*10 ⁻⁴	0.84	88.78	2.72*10 ⁻⁴	0.73	3683
V _o -SnO ₂ -8/TiO ₂	30.7	2.51*10 ⁻⁴	0.70	2753	3.15*10 ⁻⁵	0.83	2631
V _o -SnO ₂ -16/TiO ₂	29.36	4.51*10 ⁻⁴	0.73	3927	3.81*10 ⁻⁵	0.68	1321
V _o -SnO ₂ -24/TiO ₂	33.44	1.41*10 ⁻³	0.39	3362	3.32*10 ⁻³	1.00	1872

Table. S2 Comparison of the catalytic performance of V_v-SnO₂-16/TiO₂ with other PEC and PC nitrogen fixing catalysts

Photoelectro-catalysts	Light Source	Electrolyte	NH ₃ Yield ($\mu\text{g}\cdot\text{cm}^{-2}\text{ h}^{-1}$)	Faraday efficiency	References
V _v -SnO ₂ -16/TiO ₂	300 W Xe lamp, 100 mW cm ⁻²	N ₂ -saturated 0.1 M Na ₂ SO ₄	19.41	59.6	This work
Bi ₂ S ₃ /MoS ₂	300 W Xe lamp,	N ₂ -saturated 0.1 M Na ₂ SO ₄	18.5	33.2	[1]
SnO ₂ /MoS ₂	100 mW cm ⁻²	N ₂ -saturated 0.1 M Na ₂ SO ₄	19.6	40.3	[2]
BiOI-O _v	100 mW cm ⁻²	N ₂ -saturated H ₂ O	2.38	/	[3]
Ag/black Si	300 W Xe lamp, 100 mW cm ⁻²	N ₂ -saturated 0.1 M Na ₂ SO ₄	48.79	40.6	[4]
Au/black Si	300 W Xe lamp,	N ₂ -saturated 150 p.p.m Na ₂ SO ₄	1.33		[5]
TiO ₂ /Au/a-TiO ₂	300 W Xe lamp 100 mW cm ⁻²	N ₂ -saturated H ₂ O	0.228	/	[6]
O _v -TiO ₂	400 W Hg lamp	N ₂ -saturated H ₂ O	0.189		[7]

RT: room temperature; AP: atmospheric pressure

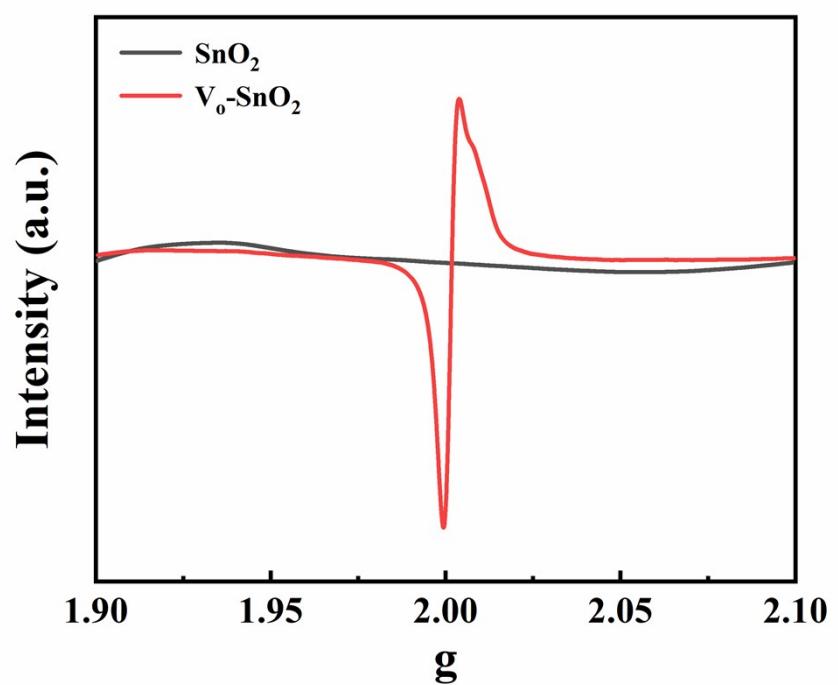


Fig. S1 EPR spectrum of SnO_2 quantum dot before and after high temperature annealing at low temperature of 90 K.

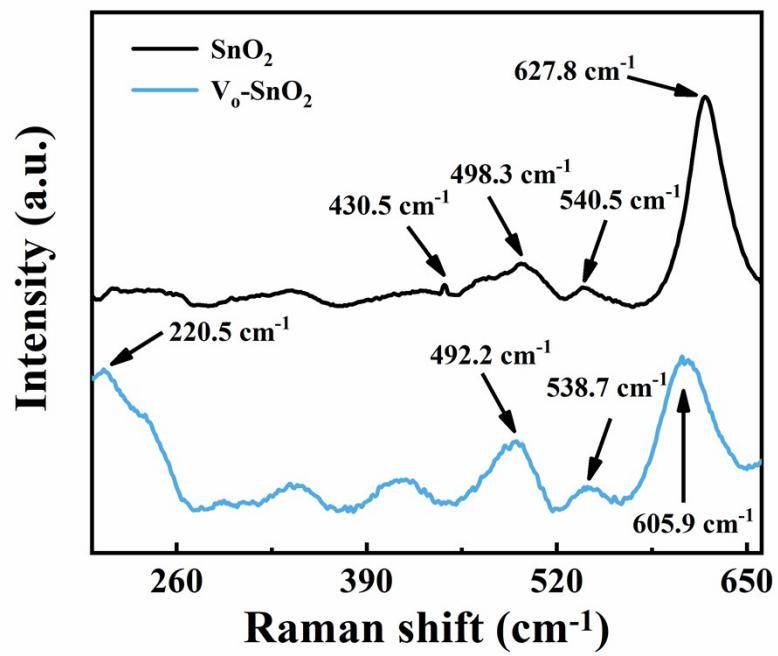


Fig. S2 Raman spectra of SnO₂ and V₀-SnO₂.

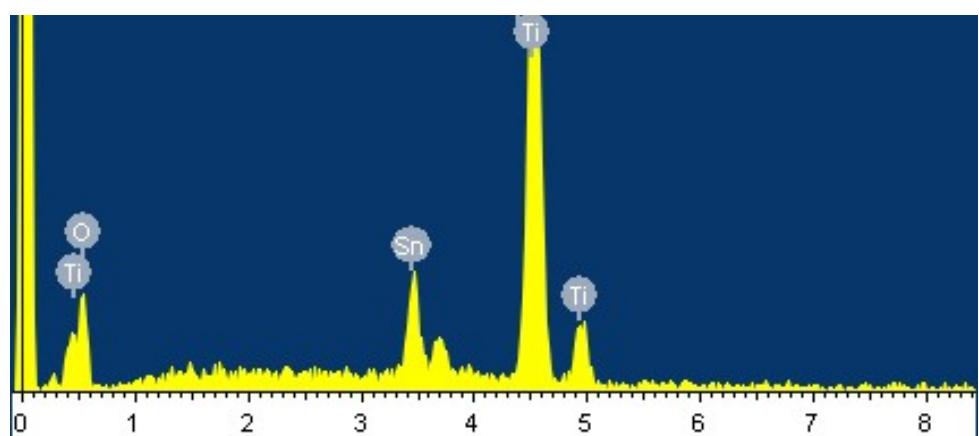


Fig. S3 EDX spectrum of $V_o\text{-SnO}_2\text{-16/TiO}_2$.

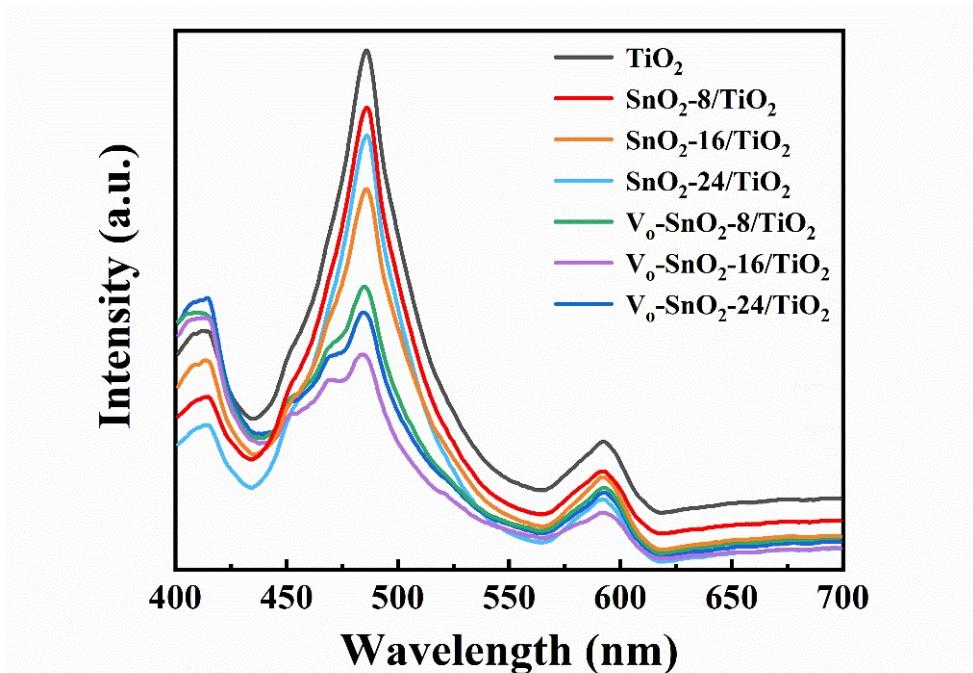


Fig. S4 Room-temperature steady-state PL spectrum of TiO_2 , $\text{SnO}_2/\text{TiO}_2$ and $\text{V}_o\text{-}\text{SnO}_2/\text{TiO}_2$.

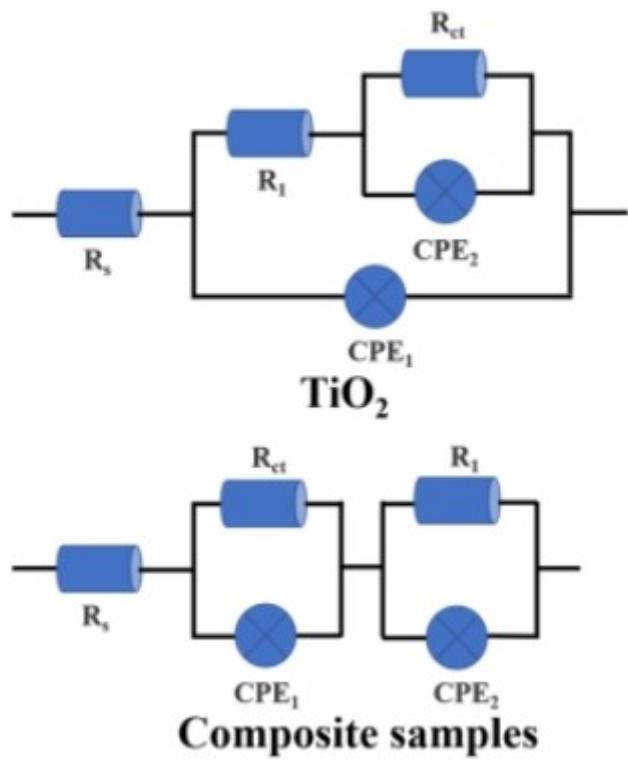


Fig. S5 Analog circuit diagram of TiO_2 and composite samples.

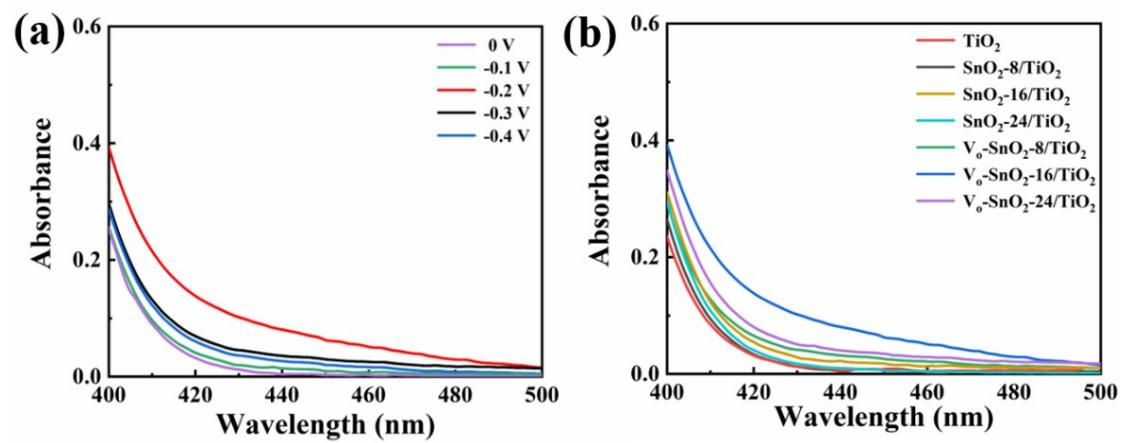
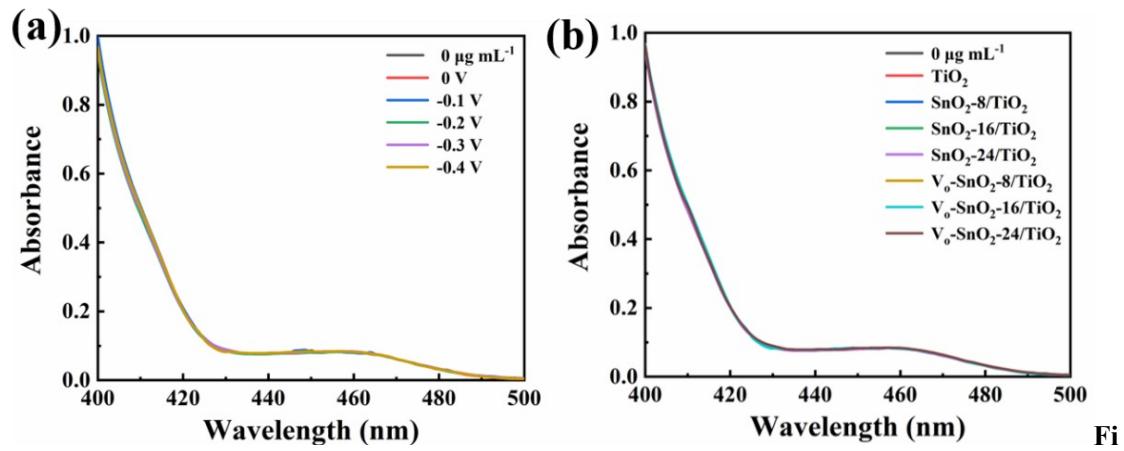


Fig. S6 Ultraviolet-visible absorption spectra of (a) V_o - SnO_2 -16/ TiO_2 at different potentials and (b) TiO_2 , SnO_2 / TiO_2 and V_o - SnO_2 / TiO_2 at -0.2 V determined by Nessler's reagent.



g. S7 Ultraviolet-visible absorption spectra of (a) V_o -SnO₂-16/TiO₂ at different potentials and (b) TiO₂, SnO₂/TiO₂ and V_o -SnO₂/TiO₂ at -0.2 V determined by Watt-Chrisp method.

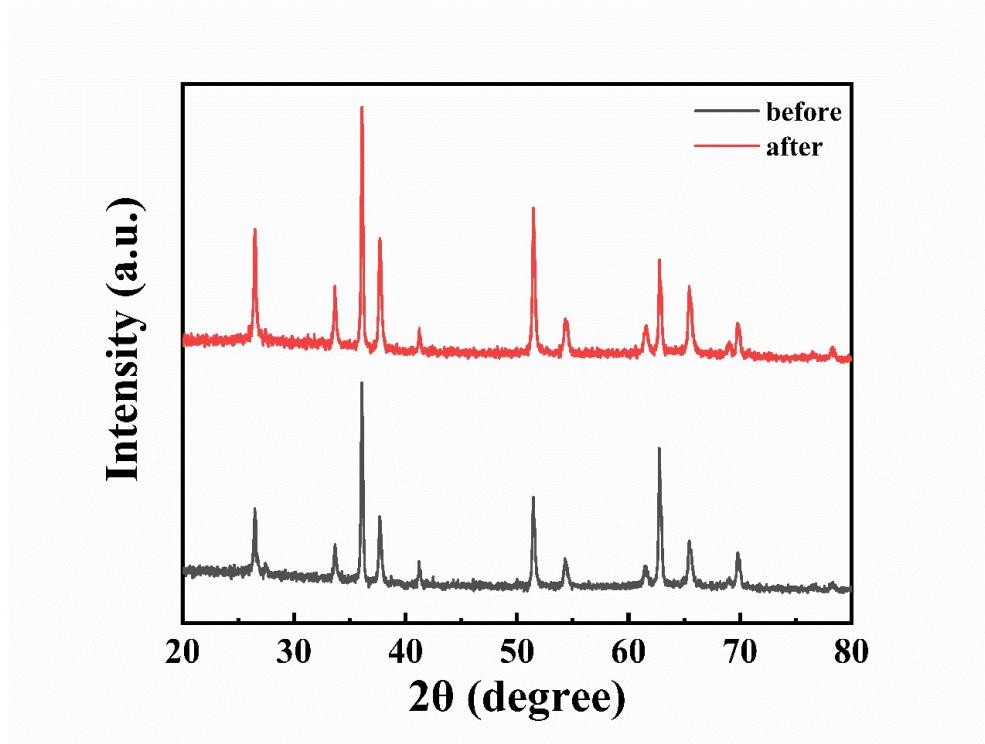


Fig.S8 XRD pattern of $\text{V}_o\text{-SnO}_2/\text{TiO}_2$ before and after 5 nitrogen fixation cycles.

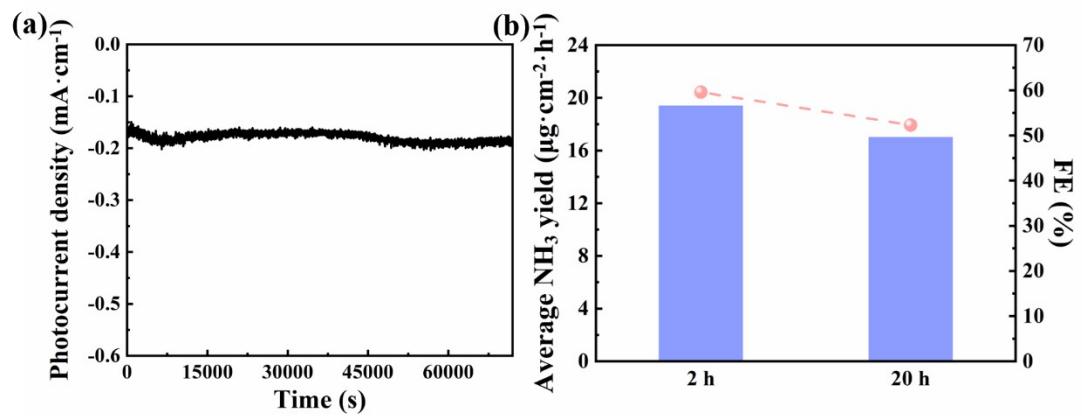


Fig. S9 (a) Chronoamperometry curve of $\text{V}_\text{o}-\text{SnO}_2-16/\text{TiO}_2$ electrolysis for 20 h at -0.2 V potential;
(b) Ammonia yield and Faraday efficiency of electrolysis for 2 h and 20 h.

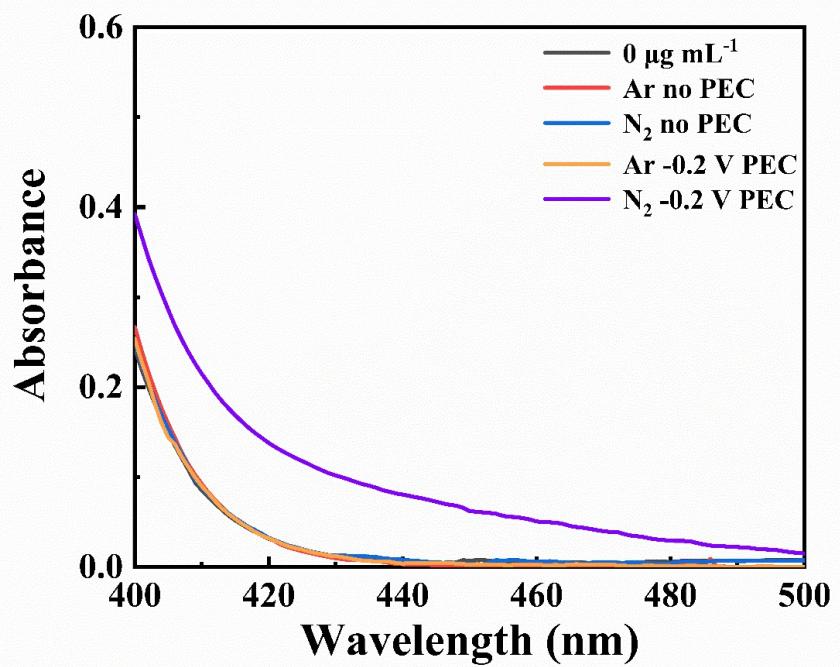


Fig. S10 Ultraviolet -visible absorption spectra of V_o-SnO₂-16/TiO₂ before and after electrolysis under different atmospheres.

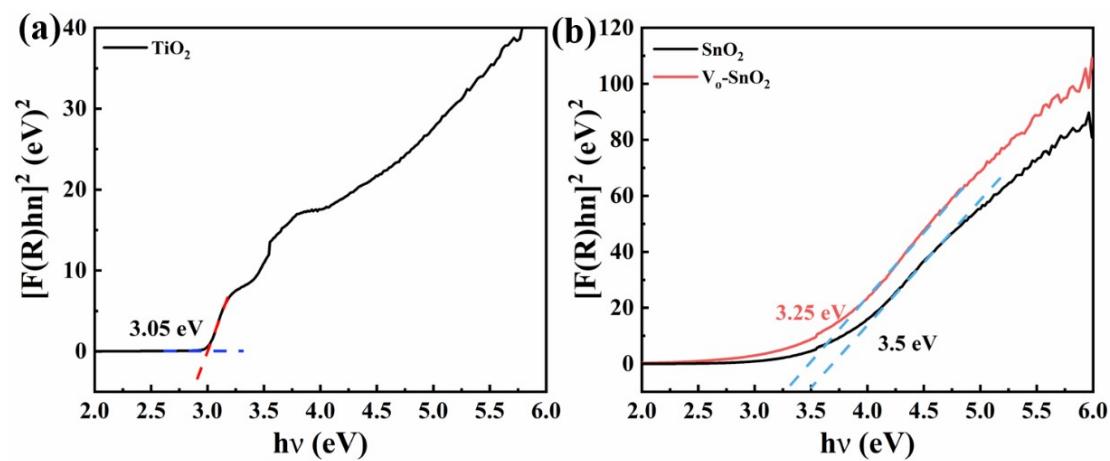


Fig. S11 The band gap of (a) TiO_2 nanorods and (b) SnO_2 and $\text{V}_o\text{-SnO}_2$ quantum dots.

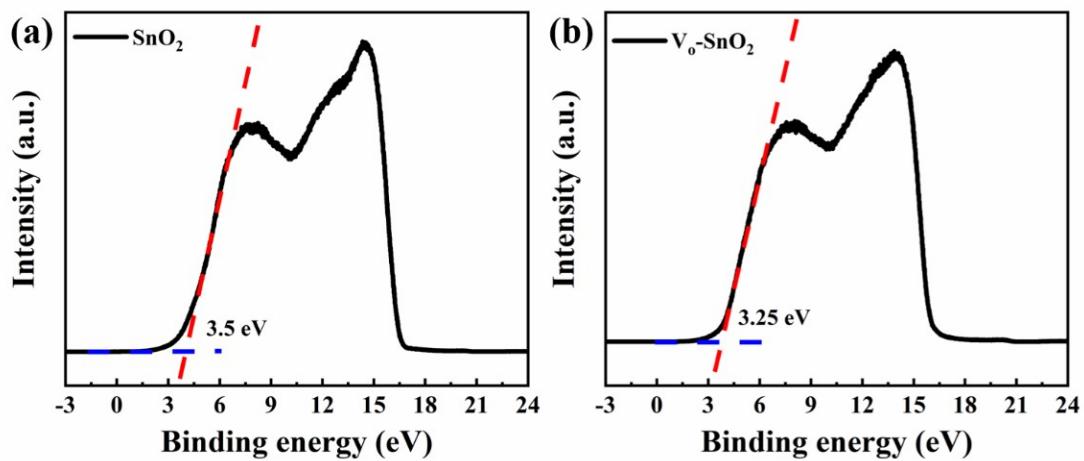


Fig. S12 UPS spectrum of (a) SnO_2 quantum dots, (b) $\text{V}_o\text{-SnO}_2$ quantum dots.

References

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